



**THE DATASHEET OF  
BQ2205LYPWRG4**







These devices have limited built-in ESD protection. The leads should be shorted together or the device placed in conductive foam during storage or handling to prevent electrostatic damage to the MOS gates.

**ORDERING INFORMATION**

<b>T<sub>A</sub></b>	<b>OPERATION</b>	<b>PART NUMBER<sup>(1)</sup></b>	<b>SYMBOL</b>
-20°C to 70°C	3.3 V	bq2205LYPW	bq2205LY

(1) The PW package is available taped and reeled. Add an R suffix to the device type (i.e. bq2205LYPWR) to order quantities of 2,000 devices per reel.

**ABSOLUTE MAXIMUM RATINGS**

over operating free-air temperature range unless otherwise noted<sup>(2)</sup>

		<b>bq2205LY</b>	<b>UNIT</b>
Input voltage range	V <sub>CC</sub> , (wrt V <sub>SS</sub> )	-0.3 to 6.0	V
	BC <sub>P</sub> , (wrt V <sub>SS</sub> )	-0.3 to 4.5	
	all other pins, (wrt V <sub>SS</sub> )	-0.3 to V <sub>CC</sub> + 0.3	
Operating temperature range, T <sub>A</sub>		-20 to 70	°C
Storage temperature, T <sub>stg</sub>		-55 to 125	
Temperature under bias, T <sub>Jbias</sub>		-40 to 85	
Lead temperature 1,6 mm (1/16 inch) from case for 10 seconds		300	

(2) Stresses beyond those listed under “absolute maximum ratings” may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under “recommended operating conditions” is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

**RECOMMENDED OPERATING CONDITIONS**

	<b>MIN</b>	<b>MAX</b>	<b>UNIT</b>
Supply voltage, V <sub>CC</sub>	3.0	3.6	V
Supply voltage from backup cell, V <sub>BC</sub>	2.0	4.0	
Low-level input voltage, V <sub>IL</sub>	-0.3	0.8	
High-level input voltage, V <sub>IH</sub>	2.2	V <sub>CC</sub> + 0.3	
$\overline{\text{RST}}$ low-level input voltage, V <sub>IL</sub>	-0.3	0.4	
$\overline{\text{RST}}$ high-level input voltage, V <sub>IH</sub>	2.2	V <sub>CC</sub> + 0.3	
Operating temperature range, T <sub>A</sub>	-20	70	°C

**ELECTRICAL CHARACTERISTICS**(T<sub>A</sub> = 25°C, V<sub>CC</sub>(min) ≤ V<sub>CC</sub> ≤ V<sub>CC</sub>(max) unless otherwise noted)

PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
VCC supply current, I <sub>CC</sub> (VCC)	V <sub>BC</sub> > V <sub>CC</sub> (MIN) CE = low CECONX = 0 mA		210	500	μA
Backup Battery Supply Current, I <sub>CC</sub> (BC)	V <sub>BC</sub> > V <sub>BC</sub> (MIN), V <sub>CC</sub> = 0 V CE = low CECONX = 0 mA		50	150	nA
Output voltage (V <sub>OUT</sub> )	I(V <sub>OUT</sub> ) = 80 mA, V <sub>CC</sub> > V(SO)	V <sub>CC</sub> -0.3			V
	I(V <sub>OUT</sub> ) = 100 μA, V <sub>CC</sub> < V(SO)	V <sub>BC</sub> -0.3			
Power fail detect voltage, V <sub>PFD</sub>		2.85	2.9	2.95	
Supply switch-over voltage, V <sub>SO</sub>	V <sub>BC</sub> > V(PFD)		V <sub>PFD</sub>		
	V <sub>BC</sub> < V(PFD)		V <sub>BC</sub>		
RST output voltage	I(RST) = 1 mA			0.4	
BW output voltage	I(BW) = 1 mA			0.4	
Input leakage current on A and CE pins		-1		1	μA
V <sub>oh</sub> CE <sub>con1,2</sub>	I <sub>oh</sub> = 0.5 mA		2.4		V
V <sub>ol</sub> CE <sub>con1,2</sub>	I <sub>ol</sub> = 2.0 mA		0.4		
Battery warning level V <sub>BW</sub>	(1)			0.677xV <sub>CC</sub>	
<b>Capacitance</b>					
Output capacitance	V <sub>OUT</sub> = 0 V			7	pF
Input capacitance	V <sub>OUT</sub> = 0 V			5	
<b>Power-Down and Power-Up Timing, Refer to Figure 1 through 3</b>					
VCC slew rate fall time, t <sub>F</sub>	3.0 V to 0.0 V	300			μs
VCC slew rate rise time, t <sub>R</sub>	V <sub>SO</sub> to V <sub>PFD</sub> (max)	100			
V <sub>PFD</sub> to RST active, t <sub>RST</sub> (reset active timeout period)		30		85	ms
Chip-enable recovery time, t <sub>CER</sub>	(2)	30		85	
Chip-enable propagation delay time to external SRAM, t <sub>CED</sub>	See Figure 2		15	25	ns
Push-button low time, t <sub>PBL</sub>	RST pin		1		μs

(1) Battery warning level is detected on power up and the BW pin is latched at t<sub>CER</sub> time after V<sub>CC</sub> passes through V<sub>PFD</sub> on power up.(2) Time during which external SRAM is write protected after V<sub>CC</sub> passes through V<sub>PFD</sub> on power up.

AC TEST CONDITIONS, INPUT PULSE LEVELS  $0\text{ V} \leq V_{IN} \leq 3\text{ V}$ ,  $t_R = t_F = 5\text{ NS}$

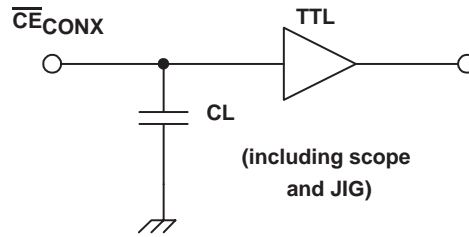


Figure 1. Output Load

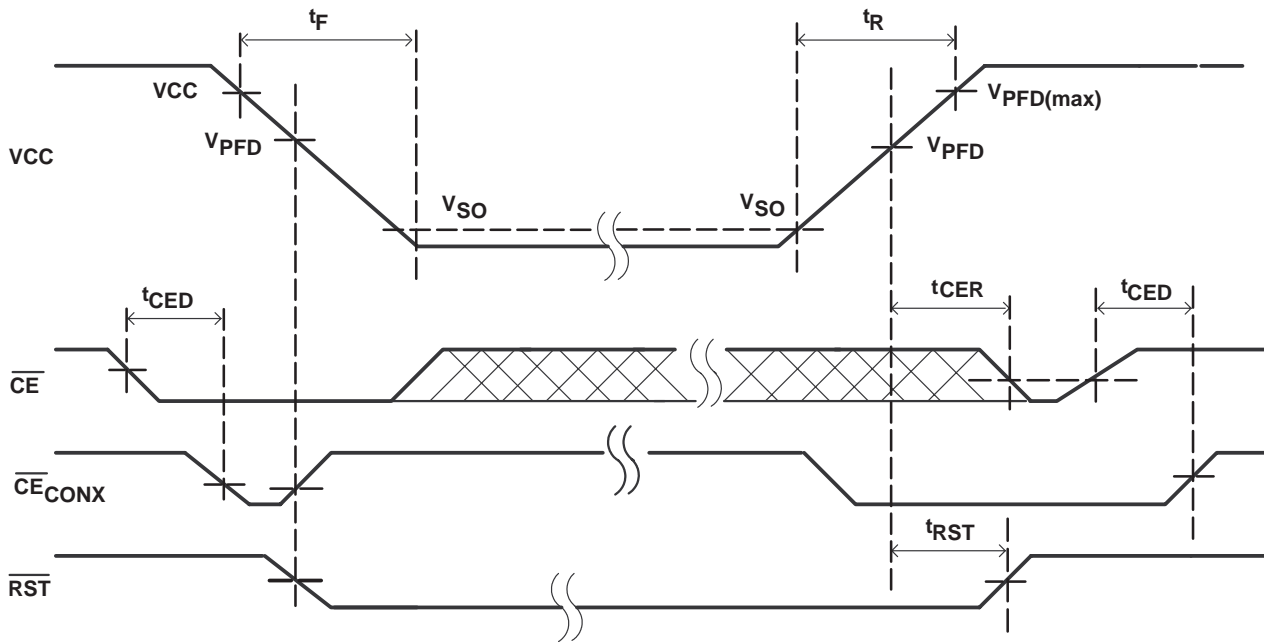


Figure 2. Power-Down/Power-Up Timing Diagram

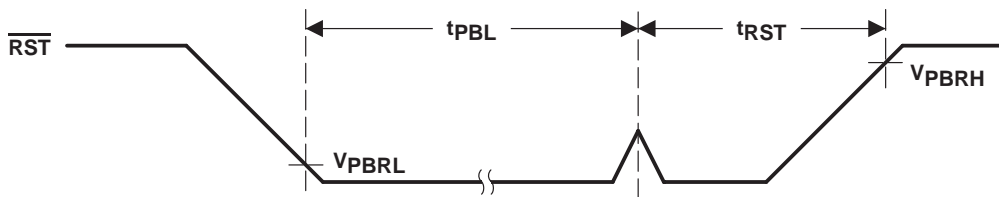
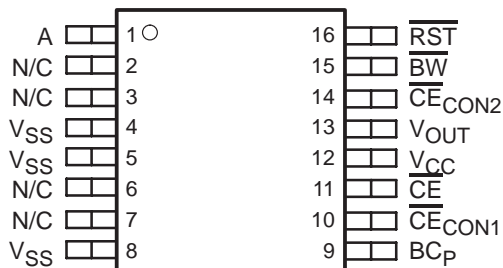


Figure 3. Push-Button Reset Timing

## TERMINAL FUNCTIONS

NAME	TERMINAL	I/O	DESCRIPTION
	bq2205LY		
A	1	I	SRAM bank select input
BC <sub>P</sub>	9	I	Backup supply input
$\overline{\text{BW}}$	15	O	Battery warning output (open-drain)
$\overline{\text{CE}}$	11	I	Chip enable input (active low)
$\overline{\text{CECON1}}$	10	O	Conditioned chip enable output 1
$\overline{\text{CECON2}}$	14	O	Conditioned chip enable output 2
N/C	2, 3, 6, 7	–	No connect. These pins must be left floating.
$\overline{\text{RST}}$	16	O	Power-up reset to system CPU output (open-drain)
V <sub>CC</sub>	12	I	Main supply input
V <sub>OUT</sub>	13	O	SRAM supply output
V <sub>SS</sub>	4, 5, 8	–	Ground input

PW PACKAGE  
(TOP VIEW)

N/C no connection

## FUNCTIONAL DESCRIPTION

Two banks of CMOS static RAM can be battery-backed using the VOUT and conditioned chip-enable output pins from the bq2205. As the voltage input VCC slews down during a power failure, the two-conditioned chip enable outputs,  $\overline{CE}_{CON1}$  and  $\overline{CE}_{CON2}$ , are forced inactive independent of the chip enable input,  $\overline{CE}$ . This activity unconditionally write-protects the external SRAM as VCC falls to an out-of-tolerance threshold  $V_{PFD}$ . As the supply continues to fall past  $V_{PFD}$ , an internal switching device forces VOUT to the backup energy source.  $\overline{CE}_{CON1}$  and  $\overline{CE}_{CON2}$  are held high by the VOUT energy source.

During power-up, VOUT is switched back to the 3.3-V supply as VCC rises above the backup cell input voltage sourcing VOUT. Outputs  $\overline{CE}_{CON1}$  and  $\overline{CE}_{CON2}$  are held inactive for time  $t_{CER}$  after the power supply has reached  $V_{PFD}$ , independent of the  $\overline{CE}$  input, to allow for processor stabilization.

During power-valid operation, the  $\overline{CE}$  input is passed through to one of the two  $\overline{CE}_{CONx}$  outputs with a propagation delay of less than  $t_{CED}$ . The  $\overline{CE}$  input is output on one of the two  $\overline{CE}_{CONx}$  output pins; depending on the level of bank select input A. See truth table below.

**Table 1. Truth Table**

INPUT		OUTPUT	
$\overline{CE}$	A	$\overline{CE}_{CON1}$	$\overline{CE}_{CON2}$
H	x	H	H
L	L	L	H
L	H	H	L

Bank select input A is usually tied to a high-order address pin so that a large nonvolatile memory can be designed using lower-density memory devices. Non-volatility and decoding are achieved by hardware hookup as shown in the application diagram.

The  $\overline{RST}$  output can be used as the power-on reset for a microprocessor. Access to the external RAM may begin when  $\overline{RST}$  returns inactive.

## BATTERY BACKUP INPUT

Backup energy source,  $BC_P$  input is provided on the bq2205 for use with an external primary cell. The primary cell input is designed to accept any 3-V primary battery (non-rechargeable), typically some type of lithium chemistry.

## Power-Down and Power-Up Cycle

The bq2205 continuously monitors VCC for out-of-tolerance. During a power failure, when VCC falls below  $V_{PFD}$ , the bq2205 write-protects the external SRAM. The power source is switched to  $BC_P$  when  $V_{CC}$  is less than  $V_{PFD}$  and  $BC_P$  is greater than  $V_{PFD}$ , or when  $V_{CC}$  is less than  $BC_P$  and  $BC_P$  is less than  $V_{PFD}$ . When VCC is above  $V_{PFD}$ , the power source is  $V_{CC}$ . Write-protection continues for  $t_{CER}$  time after VCC rises above  $V_{PFD}$ .

An external CMOS static RAM is battery-backed using the VOUT and chip enable output pins from the bq2205. As the voltage input  $V_{CC}$  slews down during a power failure, the chip enable output,  $\overline{CE}_{CONx}$ , is forced inactive independent of the chip enable input  $\overline{CE}$ .

As the supply continues to fall past  $V_{PFD}$ , an internal switching device forces VOUT to the external backup energy source.  $\overline{CE}_{CONx}$  is held high by the VOUT energy source.

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## FUNCTIONAL DESCRIPTION

During power up, VOUT is switched back to the main supply as VCC rises above the backup cell input voltage sourcing VOUT. If  $V_{PFD} < BC_P$  on the bq2205 the switch to the main supply occurs at  $V_{PFD}$ .  $\overline{CE}_{CONx}$  is held inactive for time  $t_{CER}$  after the power supply has reached  $V_{PFD}$ , independent of the  $\overline{CE}$  input, to allow for processor stabilization.

### Power-On Reset

The bq2205 provides a power-on reset, which pulls the  $\overline{RST}$  pin low on power down and remains low on power up for  $t_{RST}$  after  $V_{CC}$  passes  $V_{PFD}$ . With valid battery voltage on  $BC_P$ ,  $\overline{RST}$  remains valid for  $V_{CC} = V_{SS}$ . The pull-up resistor on this pin should not exceed 10 k $\Omega$  if a push button reset is used.

### Battery Low Warning

The bq2205 checks the battery voltage on power-up. The threshold for the battery warning comparator is  $V_{BW}$ , and a low level is sensed after power valid on each power up and latched after  $t_{CER}$  time. The latched value is presented at  $\overline{BW}$  pin where a low indicates a low battery.

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## APPLICATION INFORMATION

### PCB LAYOUT INFORMATION

It is important to pay special attention to the PCB layout. The following provides some guidelines:

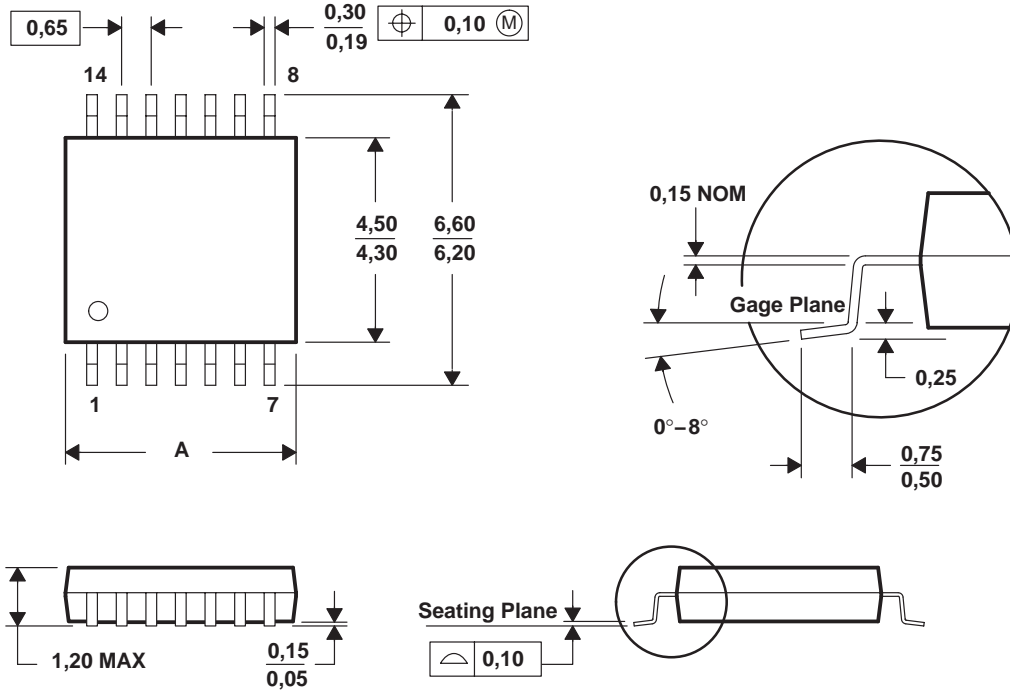
- To obtain optimal performance, the decoupling capacitor from input terminals to  $V_{SS}$  should be placed as close as possible to the bq2205, with short trace runs to both signal and  $V_{SS}$  pins.
- All low-current  $V_{SS}$  connections should be kept separate from the high-current paths from the inputs supplies. Use a single-point ground technique incorporating both the small signal ground path and the power ground path.

MECHANICAL DATA

PW (R-PDSO-G\*\*)

PLASTIC SMALL-OUTLINE PACKAGE

14 PINS SHOWN



DIM \ PINS **	8	14	16	20	24	28
A MAX	3,10	5,10	5,10	6,60	7,90	9,80
A MIN	2,90	4,90	4,90	6,40	7,70	9,60

4040064/F 01/97

- NOTES: A. All linear dimensions are in millimeters.  
 B. This drawing is subject to change without notice.  
 C. Body dimensions do not include mold flash or protrusion not to exceed 0,15.  
 D. Falls within JEDEC MO-153

**PACKAGING INFORMATION**

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead/Ball Finish (6)	MSL Peak Temp (3)	Op Temp (°C)	Device Marking (4/5)	Samples
BQ2205LYPW	ACTIVE	TSSOP	PW	16	90	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-20 to 70	2205Y	<a href="#">Samples</a>
BQ2205LYPWG4	ACTIVE	TSSOP	PW	16	90	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-20 to 70	2205Y	<a href="#">Samples</a>
BQ2205LYPWR	ACTIVE	TSSOP	PW	16	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-20 to 70	2205Y	<a href="#">Samples</a>
BQ2205LYPWRG4	ACTIVE	TSSOP	PW	16	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-20 to 70	2205Y	<a href="#">Samples</a>

(1) The marketing status values are defined as follows:

**ACTIVE:** Product device recommended for new designs.

**LIFEBUY:** TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

**NRND:** Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

**PREVIEW:** Device has been announced but is not in production. Samples may or may not be available.

**OBSELETE:** TI has discontinued the production of the device.

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check <http://www.ti.com/productcontent> for the latest availability information and additional product content details.

**TBD:** The Pb-Free/Green conversion plan has not been defined.

**Pb-Free (RoHS):** TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

**Pb-Free (RoHS Exempt):** This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

**Green (RoHS & no Sb/Br):** TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

(3) MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

(4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

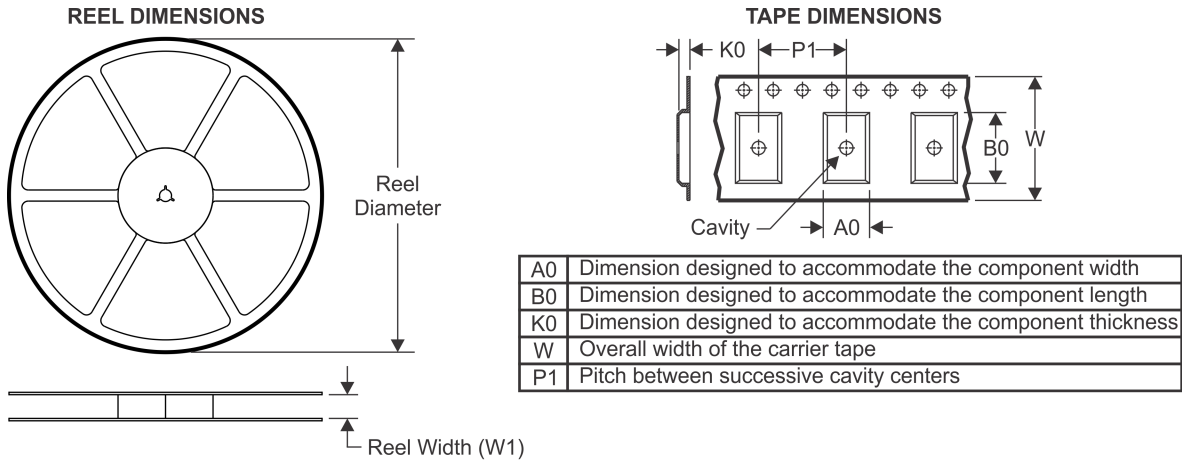
(5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

(6) Lead/Ball Finish - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead/Ball Finish values may wrap to two lines if the finish value exceeds the maximum column width.

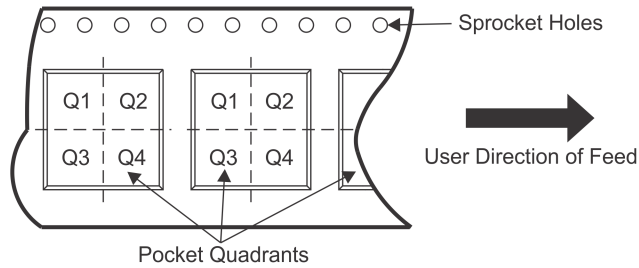
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## TAPE AND REEL INFORMATION



### QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



\*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
BQ2205LYPWR	TSSOP	PW	16	2000	330.0	12.4	6.9	5.6	1.6	8.0	12.0	Q1

TAPE AND REEL BOX DIMENSIONS



\*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
BQ2205LYPWR	TSSOP	PW	16	2000	350.0	350.0	43.0



4220204/A 02/2017

NOTES:

1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.15 mm per side.
4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.25 mm per side.
5. Reference JEDEC registration MO-153.

# EXAMPLE BOARD LAYOUT

PW0016A

TSSOP - 1.2 mm max height

SMALL OUTLINE PACKAGE



LAND PATTERN EXAMPLE  
EXPOSED METAL SHOWN  
SCALE: 10X



SOLDER MASK DETAILS

4220204/A 02/2017

NOTES: (continued)

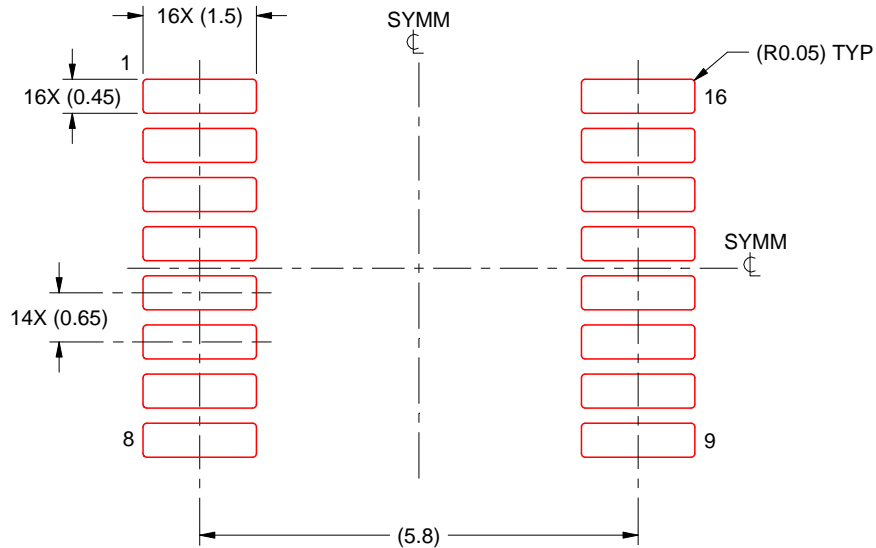
- 6. Publication IPC-7351 may have alternate designs.
- 7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.

# EXAMPLE STENCIL DESIGN

PW0016A

TSSOP - 1.2 mm max height

SMALL OUTLINE PACKAGE



SOLDER PASTE EXAMPLE  
BASED ON 0.125 mm THICK STENCIL  
SCALE: 10X

4220204/A 02/2017

NOTES: (continued)

8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
9. Board assembly site may have different recommendations for stencil design.

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